



Notice

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Introduction

Agilent Technologies E4438C ESG vector signal generator incorporates a broad array of capabilities for testing both analog and digital communications systems. Flexible options provide test solutions that will evaluate the performance of nearly all current and proposed air interface standards. Many test functions can be customized to meet the needs of proprietary and other nonstandard wireless protocols as well. You can configure your instrument to address a wide variety of tests—from altering nearly every aspect of a digital signal or signal operating environment, to creating experimental signals. This flexibility, along with an architecture that accepts future enhancements makes the E4438C ESG vector signal generator an excellent choice for wireless communications system testing now and in the future.

Choose your required frequency range as an Option when configuring your E4438C ESG E4438C ESG vector signal generator. Please refer to the E4438C Configuration Guide vector signal generator for complete ordering information. Literature number 5988-4085EN. Specifications (spec): Specifications describe the instrument's warranted performance Definitions and apply after a 45 minute warm-up. All specifications are valid over the signal generators entire operating/environmental range unless otherwise noted. Supplemental characteristics, denoted typical or nominal, provide additional [nonwarranted] information useful in applying the instrument. Column headings labeled "standard" imply that this level of performance is standard, without regard for option configuration. If a particular option configuration modifies the standard performance, that performance is given in a separate column. Typical (typ): performance is not warranted. It applies at 25°C. 80% of all products meet typical performance. Nominal (nom): values are not warranted. They represent the value of a parameter that is most likely to occur; the expected or mean value. They are included to facilitate the application of the product. Standard (std): No options are included when referring to the signal generator unless

noted otherwise.

Key standard features

- Expandable architecture
- Broad frequency coverage
- Choice of electronic or mechanical attenuator
- Superior level accuracy
- + Wideband FM and ΦM
- · Step and list sweep, both frequency and power
- Built-in function generator
- · Lightweight, rack-mountable
- 1-year standard warranty
- 2-year calibration cycle
- Broadband analog I/Q inputs
- I/Q adjustment capabilities and internal calibration routine
- · Excellent modulation accuracy and stability
- · Coherent carrier output up to 4 GHz

Optional features

- Internal baseband generator, 8 or 64 MSa (40 or 320 MB) memory with digital bus capability
- ESG digital input or output connectivity with N5102A Baseband Studio digital signal interface module
- 6 GB internal hard drive
- Internal bit error rate (BER) analyzer
- · High-stability time-base
- · Enhanced phase noise performance
- · High output power with mechanical attenuator
- Move all front panel connectors to the rear panel
- 3GPP W-CDMA FDD personality
- · cdma2000 and IS-95-A personality
- TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA)
- · Calibrated noise (AWGN) personality
- GPS personality
- Signal Studio for 1xEV-DO
- Signal Studio for 1xEV-DV and cdma2000
- · Signal Studio for 802.11 WLAN
- Signal Studio for *Bluetooth*™
- Signal Studio for enhanced multitone
- Signal Studio for HSDPA over W-CDMA
- Signal Studio for TD-SCDMA (TSM)
- Signal Studio for noise power ratio (NPR)
- Signal Studio for S-DMB
- · Signal Studio for pulse building

This document contains the measured specifications for the instrument platform and personalities. It does not contain a full list of features for all optional personalities. Please consult the individual product overviews for each personality for a full listing of all features and capabilities. These are listed at the end of this document.

Frequency

Frequency range

ion UNJ]

0.01 Hz

Frequency switching speed⁵

Frequency resolution

equency sw	ntening sp	CCU				
	S	tandard	With (Option UNJ	With Option 506	
	Freq. ³	Freq./Amp. ⁴	Freq. ³	Freq./Amp.	⁴ Freq. ³	Freq./Amp.4
Digital m	odulation					
on	(< 35 ms) (< 49 ms)	(< 35 ms) (< 52 ms)	(< 41 ms)) (< 57 ms)
off	(< 9 ms)	(< 9 ms)	(< 9 ms	(< 9 ms)	(< 16 ms	(< 17 ms)
[For hops	s < 5 MHz	within a band]				
Digital m	odulation					
on	(< 9 ms)	(< 9 ms)	(< 9 ms)	(< 9 ms)	(< 33 ms)) (< 53 ms)
off	(< 9 ms)	(< 9 ms)	(< 9 ms)	(< 9 ms)	(< 12 ms) (< 14 ms)
hase offset	Pha	se is adjustable	e remotely l	I AN GPIR	RS-2321 or via	front nanel

Phase offset Phase is adjustable remotely [LAN, GPIB, RS-232] or via front panel in nominal 0.1° increments

Sweep modes

Operating modes	Frequency step, amplitude step and arbitrary list			
Dwell time	1 ms to 60 s			
Number of points	2 to 401			

Internal reference oscillator

Stability ⁵		
	Standard	With Option UNJ or 1E5
Aging rate	< ±1 ppm/yr	< ±0.1 ppm/yr or
		< ±0.0005 ppm/day after 45 days
Temp [0 to 55° C]	(< ±1 ppm)	(< ±0.05 ppm)
Line voltage	(< ±0.1 ppm)	(< ±0.002 ppm)
Line voltage range	(+5% to –10%)	(+5% to –10%)
RF reference output		
Frequency	10 MHz	
Amplitude	4 dBm ±2 dB	
RF reference input require	ements	
	Standard	With Option UNJ or 1E5
Frequency	1, 2, 5, 10 MHz ± 10 ppm	1, 2, 5, 10 MHz ±.2 ppm
Amplitude	–3.5 dBm to 20 dBm	
Input impedance	50 Ω	

1. The E4438C is available as a vector platform only. For analog models refer to the E4420B thru E4426B.

2. Performance below 250 kHz not guaranteed.

5. Parentheses denote typical performance.

^{3.} To within 0.1 ppm of final frequency above 250 MHz or within 100 Hz below 250 MHz.

^{4.} Frequency switching time with the amplitude settled within ± 0.1 dB.

Output power

Power			
	Standard	With Option UNB	With Option 506
250 kHz to 250 MHz	+11 to -136 dBm	+15 to –136 dBm	+12 to -136 dBm
> 250 MHz to 1 GHz	+13 to -136 dBm	+17 to –136 dBm	+14 to -136 dBm
> 1 to 3 GHz	+10 to -136 dBm	+16 to -136 dBm	+13 to -136 dBm
> 3 to 4 GHz	+7 to -136 dBm	+13 to –136 dBm	+10 to -136 dBm
> 4 to 6 GHz	N/A	N/A	+10 to -136 dBm

Typical maximum available power



Level range with Attenuator Hold active

 or range with netom			
	Standard	With Option UNB	With Option 506
250 kHz to 1 GHz	23 dB	27 dB	24 dB
> 1 to 3 GHz	20 dB	26 dB	23 dB
> 3 to 4 GHz	17 dB	23 dB	20 dB
> 4 to 6 GHz	N/A	N/A	20 dB

Level accuracy [dB]

Standard ^{1,2}				
_		Power le	evel	
_	+7 to	–50 to	-110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.5	±0.5	±0.7	(±1.5)
2.0 to 3 GHz	±0.6	±0.6	±0.8	(±2.5)
3 to 4 GHz	±0.7	±0.7	±0.9	(±2.5)

With Option UNB^{2,3}

_	Power level			
	+10 to	–50 to	–110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.5	±0.7	±0.8	(±1.5)
2.0 to 3 GHz	±0.6	±0.8	±1.0	(±2.5)
3 to 4 GHz	±0.8	±0.9	±1.3	(±2.5)

temperature range. Accuracy degrades by 0.3 dB above +7 dBm and by 0.8 dB above +10 dBm With Option 506^{2, 4}

above +7 dBm, and by 0.8 dB above +10 dBm. 2. Parentheses denote typical performance.

 Quoted specifications for 23 °C ± 5 °C. Accuracy degrades by less than 0.03 dB/°C over full temperature range. Accuracy degrades by 0.2 dB above +10 dBm, and by 0.8 dB above +13 dBm.

1. Quoted specifications for 23 °C ± 5 °C. Accuracy degrades by less than 0.03 dB/°C over full

4. Quoted specifications for 23 °C \pm 5 °C. Accuracy degrades by less than 0.02 dB/°C over full temperature range. Accuracy degrades by 0.2 dB above +7 dBm.

_	Power level			
	+7 to	–50 to	–110 to	< –127 dBm
	–50 dBm	–110 dBm	–127 dBm	
250 kHz to 2.0 GHz	±0.6	±0.8	±0.8	(±1.5)
2.0 to 3 GHz	±0.6	±0.8	±1.0	(±2.5)
3 to 4 GHz	±0.8	±0.9	±1.5	(±2.5)
4 to 6 GHz	±0.8	±0.9	(±1.5)	

-	vith digital modulation	•	elative to CW]		
Conditions:	[with PRBS modulated data;				
	if using I/Q inputs, $$	$l^2 + Q^2 = 0.5$	5 V _{rms} , nominal] ¹		
Level accuracy w	vith ALC on				
$\pi/4$ DQPSK	or QPSK formats				
Conditions:	With raised cosine or	root-raised	cosine filter and a ≥	2 0.35;	
	with 10 kHz \leq symbol	rate $\leq 1 \text{ MH}$	Iz; at RF freq ≥ 25 N	IHz;	
	power ≤ max specifie	d –3 dB			
	Standard	Vith Option S	506		
	±0.15 dB ±	±0.25 dB			
Constant am	plitude formats [FSK, G	GMSK, etc]			
	Standard	Nith Option !	506		
	±0.15 dB ±0.20 dB				
Level accuracy w	vith ALC off $1, 2$ (±0.15)	dB) [relative	to ALC on]		
Conditions:	After power search is executed, with burst off.				
Level switching s	speed ¹				
-		Standard	With Option UNB	With Option 50	
Normal oper	ation [ALC on]	(< 15 ms)	(< 21 ms)	(< 21 ms)	
When using	power search manual	(< 83 ms)	(< 95 ms)	(< 95 ms)	
0	•	. ,	. ,	. ,	

(< 103 ms)

(< 119 ms)

(< 119 ms)

When using power search auto

1. Parentheses denote typical performance.

^{2.} When applying external I/Q signals with ALC off, output level will vary directly with I/Q input level.



Repeatability measures the ability of the instrument to return to a given power setting after a random excursion to any other frequency and power setting. It is a relative measurement that reflects the difference in dB between the maximum and minimum power readings for a given setting over a specific time interval. It should not be confused with absolute power accuracy, which is measured in dBm.¹



Relative level accuracy measures the accuracy of a step change from any power level to any other power level. This is useful for large changes (i.e. 5 dB steps).¹



Spectral purity

SSB Phase noise [at]	20 kHz offse	t] ¹	
	Standard		With Option UNJ
at 500 MHz	(< -124	dBc/Hz)	< –135 dBc/Hz, (< –138 dBc/Hz)
at 1 GHz	(< –118	dBc/Hz)	<-130 dBc/Hz, (<-134 dBc/Hz)
at 2 GHz	(< -112	dBc/Hz)	< –124 dBc/Hz, (< –128 dBc/Hz)
at 3 GHz	(< -106	dBc/Hz)	< –121 dBc/Hz, (< –125 dBc/Hz)
at 4 GHz	(< -106	dBc/Hz)	< –118 dBc/Hz, (< –122 dBc/Hz)
at 6 GHz	N/A		< -113 dBc/Hz, (< -117 dBc/Hz)
Residual FM ¹ [CW m	ode, 0.3 to 3	kHz BW, CC	ITT, rms]
Option UNJ		< N x 1 Hz	(< N x 0.5 Hz) ²
Standard			
Phase nois	e mode 1	< N x 2 Hz	
Phase nois	e mode 2	< N x 4 Hz	

Harmonics^{1, 6} [output level \leq +4 dBm, \leq +7.5 dBm Option UNB, \leq +4.5 dBm Option 506] < -30 dBc above 1 GHz, (< -30 dBc 1 GHz and below)

Nonharmonics^{1, 3} [\leq +7 dBm output level, \leq +4 dBm Option 506]

	Standard ⁴	With Option UNJ ⁵		
	> 3 kHz	> 10 kHz	> 3 kHz	> 10kHz
	offset	offset	offset	offset
250 kHz to 250 MHz	<53 dBc (<68 dBc)	(< –58 dBc)	<65 dBc	(< –58 dBc)
250 MHz to 500 MHz	<	(<81 dBc)	<80 dBc	< –80 dBc
500 MHz to 1 GHz	<53 dBc (<68 dBc)	(< –75 dBc)	<80 dBc	< –80 dBc
1 to 2 GHz	<47 dBc (<62 dBc)	(<69 dBc)	<74 dBc	< –74 dBc
2 to 4 GHz	< -41 dBc (< -56 dBc)	(<63 dBc)	<68 dBc	< –68 dBc
4 to 6 GHz	N/A N/A	N/A	<62 dBc	<62 dBc

Subharmonics

	Standard	With Option UNJ	
≤1 GHz	None	None	
>1 GHz	< -40 dBc	None	
litter in ull1,7,8			

			0, 1, 1	1464 6 1141
Carrier	SONET/SDH	rms jitter	Standard	With option UNJ
frequency	data rates	bandwidth	(µUI rms)	(µUI rms)
155 MHz	155 MB/s	100 Hz to 1.5 MHz	(359)	(78)
622 MHz	622 MB/s	1 kHz to 5 MHz	(158)	(46)
2.488 GHz	2488 MB/s	5 kHz to 15 MHz	(384)	(74)

ter in seconds ¹	, 7, 8			
Carrier	SONET/SDH	rms jitter	Standard	With option UNJ
frequency	data rates	bandwidth	Jtanuaru	
155 MHz	155 MB/s	100 Hz to 1.5 MHz	(2.4 ps)	(0.6 ps)
622 MHz	622 MB/s	1 kHz to 5 MHz	(255 fs)	(74 fs)
2.488 GHz	2488 MB/s	5 kHz to 15 MHz	(155 fs)	(30 fs)

1. Parentheses denote typical performance.

^{2.} Refer to frequency bands on page 12 for N values.

^{3.} Spurs outside the operating range of the instrument are not specified.

^{4.} Specifications apply for FM deviations < 100 kHz and are not valid on ΦM. For non-constant amplitude formats, unspecified spur levels occur up to the second harmonic of the baseband rate.

^{5.} Specifications apply for CW mode only.

 $[\]mbox{6. Harmonic performance outside the operating range of the instrument is typical. } \label{eq:constraint}$

^{7.} Calculated from phase noise performance in CW mode only at -2.5 dBm for standard instruments, -0.5 dBm with Option 506, and +2.5 dBm with Option UNB.

^{8.} For other frequencies, data rates, or bandwidths, please contact your sales representative.



Frequency bands

Band	Frequency range	N number
1	250 kHz to \leq 250 MHz	1
2	> 250 MHz to ≤ 500 MHz	0.5
3	$>$ 500 MHz to \leq 1GHz	1
4	$>$ 1 to \leq 2 GHz	2
5	> 2 to ≤ 4 GHz	4
6	$>$ 4 to \leq 6 GHz	8

Frequency modulation^{1,4}

Maximum deviation ²			
	<i>Standard</i> N x 8 MHz	<i>With Optior</i> N x 1 MHz	n UNJ
Resolution	0.1% of devi whichever is	ation or 1 Hz, s greater	
Modulation frequency i	r ate ⁵ (deviatio	on = 100 kHz]	
Coupling	1 dB bandw	idth	3 dB bandwidth
FM path 1[DC]	DC to 100 kl	Ηz	(DC to 10 MHz)
FM path 2 [DC]	DC to 100 kł	Ηz	(DC to 0.9 MHz)
FM path 1 [AC]	20 Hz to 100	kHz	(5 Hz to 10 MHz)
FM path 2 [AC]	20 Hz to 100	kHz	(5 Hz to 0.9 MHz)
Deviation accuracy ² [1	kHz rate, devia	tion < N x 100	kHz]
	< ± 3.5% of	FM deviation	+ 20 Hz
Carrier frequency accu		t o CW in DCF t deviation + (
Distortion ² [1 kHz rate,	dev.= N x 100 < 1%	kHz]	
FM using external inpu	ts 1 or 2		
Sensitivity	1 V _{peak} for indicated deviation		
Input impedance	$50 \ \Omega$, nominal		
•	mited to a max	ximum rate of	lly for composite modulation. 1 MHz. The FM 2 path must be

^{1.} All analog performance above 4 GHz is typical.

^{2.} Refer to frequency bands on this page to compute specifications.

^{3.} At the calibrated deviation and carrier frequency, within 5 °C of ambient temperature at time of calibration.

^{4.} For non-Option UNJ units, specifications apply in phase noise mode 2 [default].

^{5.} Parentheses denote typical performance.

Phase modulation 1, 5

Resolution	0.1% of set d	eviation			
Modulation freque	ncy response ^{2, 7}				
Standard					
	Maximum	Allowable	rates [3 dB BW]		
Mode	deviation	ΦM path 1	ΦM path 2		
Normal BW	N x 80 rad	DC to 100 kHz	DC to 100 kHz		
High BW ⁶	N x 8 rad	(DC to 1 MHz)	(DC to 0.9 MHz)		
	N x 1.6 rad	(DC to 10 MHz)	(DC to 0.9 MHz)		
With Option UNJ					
	Maximum	Allowable	rates [3 dB BW]		
Mode	deviation	ΦM path 1	ΦM path 2		
Normal BW	N x 10 radians	DC to 100 kHz	DC to 100 kHz		
High BW	N x 1 radians	(DC to 1 MHz)	(DC to 0.9 MHz)		
Deviation accuracy	Deviation accuracy [1 kHz rate, Normal BW mode]				
$< \pm 5\%$ of deviation + 0.01 radians					
-	rate, deviation < 80 UNJ models, Norma < 1%		odel, < 10N radians on		
$\Phi {f M}$ using externa	l inputs 1 or 2				
Sensitivity	1 V _{peak} for in	1 V _{peak} for indicated deviation			
Input impedan	nce 50 Ω , nomina	50 Ω , nominal			
Paths	modulation.	ΦM path 1 and ΦM path 2 are summed internally for composite modulation. The ΦM 2 path is limited to a maximum rate of 1 MHz. ΦM path 2 must be set to a deviation less than the ΦM path 1.			

Amplitude modulation^{1, 3}

[fc > 500 kHz]

Range	0 to 100%	
Resolution	0.1%	
Rates [3 dB bandwidth	1]	
DC coupled	0 to 10 kHz	
AC coupled	10 Hz to 10 kHz	
Accuracy ^{4, 7}	1 kHz rate <±(6% of setting +1%)	
Distortion ^{4, 7} [1 kHz ra	ite, THD]	
St	andard/Option UNJ Option 506	
30% AM	< 1.5% < 1.5%	
90% AM	(< 4%) (< 5%)	
AM using external inp	puts 1 or 2	
Sensitivity	1 V _{peak} to achieve indicated depth	
Input impedance	50 Ω, nominal	
Paths	AM path 1 and AM path 2 are summed internally for composite modulation.	

1. All analog performance above 4 GHz is typical.

2. Refer to frequency bands on page 12 for N.

- 5. For non-Option UNJ units, specifications apply in phase noise mode 2 [default].
- 6. Bandwidth is automatically selected based on deviation.

7. Parentheses denote typical performance.

^{3.} AM is typical above 3 GHz or if wideband AM or I/Q modulation is simultaneously enabled.

^{4.} Peak envelope power of AM must be 3 dB less than maximum output power below 250 MHz.

Wideband AM

Pulse modulation

	1		
Rates [1 dB bandwidth]			
ALC on ALC off	(400 Hz to 40 MHz) (DC to 40 MHz)		
	(
Wideband AM using ex	cternal I input only		
Sensitivity	0.5 V = 100%		
Input impedance	50 Ω, nominal		
On/off ratio ¹			
\leq 4 GHz	> 80 dB		
> 4 GHz	(> 64 dB)		
Rise/fall times ¹	(150 ns)		
Minimum width ¹			
ALC on	(2 µs)		
ALC off	(0.4 µs)		
Pulse repetition freque	ncy ¹		
ALC on	(10 Hz to 250 kHz)		
ALC off	(DC to 1.0 MHz)		
	tive to CW at \leq 4 dBm standard, \leq 7.5 dBm Option UNB, i dBm Option 506] (< ±1 dB)		
Pulse modulation using	j external inputs		
Input voltage			
RF on	> +0.5 V, nominal		
RF off	< +0.5 V, nominal		
Input impedance	50 Ω, nominal		
Internal pulse generato Square wave rate Pulse	or 0.1 Hz to 20 kHz		
Period	8 µs to 30 seconds		
Width	4 μs to 30 seconds		
Resolution	2 µs		

2. With ALC off, specifications apply after the execution of power search. With ALC on, specifications apply for pulse repetition rates \leq 10 kHz and pulse widths \geq 5 µs.

^{1.} Parentheses denote typical performance.

Internal analog modulation source

[Provides FM, AM, pulse, and phase modulation signals and LF audio out]

Waveforms	sine, square, ramp, triangle, pulse, noise	
Rate range		
Sine	0.1 Hz to 100 kHz	
Square, ramp, triangle	0.1 Hz to 20 kHz	
Resolution	0.1 Hz	
Frequency accuracy	same as RF reference source	
Swept sine mode [frequency, pl	hase continuous]	
Operating modes	Triggered or continuous sweeps	
Frequency range	0.1 Hz to 100 kHz	
Sweep time	1 ms to 65 sec	
Resolution	1 ms	
Dual sinewave mode		
Frequency range	0.1 Hz to 100 kHz	
Amplitude ratio	0 to 100%	
Amplitude ratio resolution	0.1%	
LF audio out mode		
Amplitude	0 to 2.5 V $_{\text{peak}}$ into 50 Ω	
Output impedance 50 Ω nominal		

External modulation inputs

Modulation types Ext 1 Ext 2

FM, ΦM , AM, pulse, and burst envelope FM, ΦM , AM, and pulse

High/Low Indicator [100 Hz to 10 MHz BW, AC coupled inputs only]. Activated when input level error exceeds 3% [nominal].

Input voltage			
RF On	0 V		
RF Off	-1.0 V		
Linear control range	0 to -1 V		
On/off ratio ¹			
Condition: V _{in} below –1	.05 V		
	\leq 4 GHz	> 75 dB	
	> 4 GHz	(> 64 dB)	
Rise/fall time ¹			
Condition: With rectang	ular input		
	(< 2 µs)		
Minimum burst repetition fr	equency ¹		
ALC on	(10 Hz)		
ALC off	DC		
Input port	External 1		
Input impedance	50 Ω , nominal		

Composite modulation

External burst envelope

AM, FM, and Φ M each consist of two modulation paths which are summed internally for composite modulation. The modulation sources may be any two of the following: Internal, External 1, External 2.

Simultaneous modulation

Multiple modulation types may be simultaneously enabled. For example, W-CDMA, AM, and FM can run concurrently and all will affect the output RF. This is useful for simulating signal impairments. There are some exceptions: FM and Φ M cannot be combined; AM and Burst envelope cannot be combined; Wideband AM and internal I/Q cannot be combined. Two modulation types cannot be generated simultaneously by the same modulation source.

^{1.} Parentheses denote typical performance.

I/Q modulation bandwidth

I/Q inputs

Input impedance Full scale input¹

```
\frac{50 \ \Omega \text{ or } 600 \ \Omega}{\sqrt{I^2 + Q^2}} = 0.5 \ V_{rms}
```





I/Q bandwidth using internal I/Q source (Options 001, 002, 601, 602)



^{1.} The optimum I/Q input level is $\sqrt{1^2+Q^2} = 0.5 V_{rms}$. I/Q drive level affects EVM, origin offset, spectral regrowth, and noise floor. Typically, level accuracy with ALC on will be maintained with drive levels between 0.25 and 1.0 V_{rms}.

^{2.} Parentheses denote typical performance.

I/Q adjustments

Source	Parameter	Range
I/Q baseband inputs	Impedance	50 or 600 Ω
	l offset [600 Ω only]	± 5 V
	Q offset [600 Ω only]	± 5 V
I/Q baseband outputs	I/Q offset adjustment	
	I/Q offset resolution	1 mV
	I/Q gain balance	± 4 dB
	I/Q attenuation	0 to 40 dB
	I/Q low pass filter	40 MHz, thru
RF output	I/Q offset adjustment	
	I/Q gain balance	± 4 dB
	I/Q attenuation	0 to 40 dB
	I/Q quad skew [≤ 3.3 GHz]	± 10°
	[≤ 3.3 GHz] [> 3.3 GHz]	± 10 + 5°
	I/Q low pass filter	2.1 MHz, 40 MHz, thru
Q baseband outputs ¹		
Differential outputs	I, Ī, Q, Q	
Single ended	Ι, Ο	
Frequency range		MHz [with sinewave]
Output voltage into 50 Ω		?) [with sinewave]
Output impedance	50 Ω non	ninal

Baseband generator [arbitrary waveform mode] [Option 601 or 602]

Channels	2 [l and Q]			
Resolution	16 bits [1/65,536]			
Arbitrary waveform memory				
Maximum playback capacity	8 megasamples (MSa)/channel [Option 601] 64 MSa/channel [Option 602]			
Maximum storage capacity	1 GSa [Option 005] 3 MSa [Standard]			
Waveform segments	· · ·			
Segment length	60 samples to 8 or 64 MSa			
Maximum number of segments	1,024 [8 MSa volatile memory] 8,192 [64 MSa volatile memory]			
Minimum memory allocation	256 samples or 1 KB blocks			
Waveform sequences				
Maximum total number of segme stored in the non-volatile	ent files			
file system	16,384			
Sequencing	Continuously repeating			
Maximum number of sequences	s 16,384 [shared with number of segments]			
Maximum segments/sequence	32,768 [including nested segments]			
Maximum segment repetitions	65.536			

Clock	
Sample rate	1 Hz to 100 MHz
Resolution	0.001 Hz
Accuracy	Same as timebase +2 ⁻⁴² [in non-integer applications
Baseband filters	
40 MHz	used for spur reduction
2.1 MHz	used for ACPR reduction
Through	used for maximum bandwidth
Reconstruction filter: [fixed]	
50 MHz	[used for all symbol rates]
Baseband spectral purity ¹	
[full scale sinewave]	
Harmonic distortion 100 kHz to 2 MHz	
	(<−65 dBc)
Phase noise	(< –127 dBc/Hz)
[baseband output of 10 MHz s	sinewave at 20 kHz offset]
IM performance	(< −74 dB)
[two sinewaves at 950 kHz an	d 1050 kHz at baseband]
Triggers	
Types	Continuous, single, gated, segment advance
Source	Trigger key, external, remote [LAN, GPIB, RS-232]
	Naativa nasitiva
External polarity	Negative, positive
External delay time	10 ns to 40 sec plus latency
External delay time External delay resolution Markers	10 ns to 40 sec plus latency 10 ns
External delay time External delay resolution Markers [Markers are defined in a segment	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.]
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.]
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type]
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier]	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier]	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Modulation	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] PSK QAM	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] PSK QAM	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data Multitone	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256 Selectable: 2, 4, 8, 16 Random ONLY
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data Multitone Number of tones	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256 Selectable: 2, 4, 8, 16 Random ONLY 2 to 64, with selectable on/off state per tone
External delay time External delay resolution Markers [Markers are defined in a segment ESG front panel. A marker can also Marker polarity Number of markers Multicarrier Number of carriers Frequency offset [per carrier] Power offset [per carrier] Power offset [per carrier] Modulation PSK QAM FSK MSK Data Multitone	10 ns to 40 sec plus latency 10 ns during the waveform generation process, or from the be tied to the RF blanking feature of the ESG.] Negative, positive 4 Up to 100 [limited by a max bandwidth of 80 MHz depending on symbol rate and modulation type] -40 MHz to +40 MHz 0 dB to -40 dB BPSK, QPSK, 0QPSK, π/4DQPSK, 8PSK, 16PSK, D8PSK 4, 16, 32, 64, 256 Selectable: 2, 4, 8, 16 Random ONLY

Baseband generator

[real-time mode] [Option 601 or 602]

	types [custom format]						
PSK	BPSK, QPSK, OQPSK,						
MSK	User-defined phase offset from 0 to 100°						
0AM	4, 16, 32, 64, 256						
FSK	Selectable: 2, 4, 8, 16 level symmetric, C4FM						
	User defined: Custom map of up to 16 deviation levels						
	Symbol rate	Maximum dev	viation				
	< 5 MHz	4 times symbo	ol rate				
	> 5 MHz, < 50 MHz	20 MHz					
	Resolution: 0.1 Hz						
/ Q Custom	map of 256 unique value	es					
IR filter							
Selectable	Nyquist, root Nyquist, a: 0 to 1, B _h T: 0.1 to 1	Gaussian, rectan	gular, Apco 25				
Custom FIR		64 overhold long	, automatically resampled t				
	1024 coefficients [max		, automatically resampled t				
	> 32 to 64 symbol filte						
		•					
	> 16 to 32 symbol filte						
	Internal filters switch between 25 and 50 M		imbol rate is				
Symbol rate							
•	serial data, symbol rate is	s adiustable					
	mbols/sec to a maximur		50 Mbits/sec				
			#bits/symbol				
from 1000 sy							
from 1000 sy For internally	generated data, symbol	rate is adjustable	from 1000 symbols/sec to				
from 1000 sy For internally 50 Msymbols	generated data, symbol	rate is adjustable	from 1000 symbols/sec to				
from 1000 sy For internally 50 Msymbols	y generated data, symbol s/sec. and a maximum of high symbol rates.	rate is adjustable	from 1000 symbols/sec to				
from 1000 sy For internally 50 Msymbols degraded at l	y generated data, symbol s/sec. and a maximum of high symbol rates.	rate is adjustable f 8 bits per symbo	from 1000 symbols/sec to I. Modulation quality may b				
from 1000 sy For internally 50 Msymbols degraded at l	r generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha	rate is adjustable f 8 bits per symbo se locked to an e	from 1000 symbols/sec to I. Modulation quality may b xternal reference.				
from 1000 sy For internally 50 Msymbols degraded at l	r generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha	rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz ii	from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma2000 ^{1,}				
from 1000 sy For internally 50 Msymbols degraded at I Baseband referen	y generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha 13 MHz for GSM, 250 ECL, CMOS, TTL comp	rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz ii	from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma2000 ¹				
from 1000 sy For internally 50 Msymbols degraded at l Baseband referen Input	y generated data, symbol s/sec. and a maximum of high symbol rates. Ice frequency Data clock can be pha 13 MHz for GSM, 250 ECL, CMOS, TTL comp	rate is adjustable f 8 bits per symbo se locked to an e kHz to 100 MHz ii	from 1000 symbols/sec to I. Modulation quality may b xternal reference. n W-CDMA and cdma20001				

^{1.} Performance below 1 MHz not specified.

^{2.} When used, this baseband reference is independent of the 10 MHz RF reference.

Data types					
	enerated data				
, 0	andom patterns	PN9, PN11, PN15, PN20, PN23			
Repeating	g sequence	Any 4-bit sequence			
		Other fixed patterns			
Direct-patte	rn RAM [PRAM]				
Max size	Option 601	8 Mbits			
	Option 602	64 Mbits			
		[each bit uses an entire sample space]			
Use	Non-standard framing				
User file					
Max size	Option 601	800 KB			
	Option 602	6.4 MB			
Use	Continuous modulation or i	nternally generated TDMA standard			
Externally g	enerated data				
Туре	Serial data				
Inputs	Data, bit clock, symbol syn	c			
	Accepts data rates ±5% of	specified data rate			
Internal burst sh	ape control				
Varies with	standards and bit rates				
Rise/fall	time range	Up to 30 bits			
Rise/fall	delay range	0 to 63.5 bits			

Specifications for Signal Personality Characteristics

3GPP W-CDMA [arbitrary waveform mode ²] [Option 400]	Error vector magnitude 1[1.8 GHz < f_c < 2.2 GHz, root Nyquist filters, 40 MHz baseband filter,EVM optimization mode, 3.84 Mcps chip rate, ≤ 4 dBm, ≤ 7 dBm with Option UNB]1 DPCH $\leq 1.8\%$, (0.9%)
	Level accuracy [relative to CW at 800, 900, 1800, 1900, 2200 MHz] ¹ [\leq 2.5 dBm standard, 7.5 dBm for Option UNB, and 4.5 dBm for Option 506] ±0.7 dB (±0.35 dB)
	Adjacent channel leakage ratio1 $[1.8 \text{ GHz} < f_c < 2.2 \text{ GHz}, default W-CDMA filters, 3.84 Mcps chip rate,$
	Alternate channel leakage ratio1 $[1.8 \text{ GHz} < f_c < 2.2 \text{ GHz}$, default W-CDMA filters, 3.84 Mcps chip rate, $\leq 2.5 \text{ dBm standard}$, $\leq 4.5 \text{ dBm Option 506}$, $\leq 7.5 \text{ dBm Option UNB}$,in Optimize ALT mode]1 DPCH-71 dBc (-75 dBc)Test Model 1-70 dBc (-73 dBc)+ 64 DPCH

1. Parentheses denote typical performance.

2. Valid for 23° $\pm 5^\circ$ C.

IS-95 CDMA

[arbitrary waveform mode²] [Option 401]

Spurious emissions

[dBc, IS-95 modified filter with equalizer and amplitude = \leq -5 dBm standard, \leq -3 dBm for Option 506, \leq 0 dBm for Option UNB]¹

0.885 to	1.25 MHz	1.25 to	1.98 MHz	1.98 to 5 MHz	
Standard	Option 506	Standard	Option 506	Standard	Option 506
(74)	(74)	(–77)	(-77)	(-77)	(-77)
-73 (-77)	-73 (-77)	(-81)	(-81)	(-85)	(-85)
-76 (-79)	-75 (-79)	(-83)	(-83)	(-85)	(-85)
(—70)	(—70)	(73)	(73)	(76)	(76)
-73 (-76)	-73 (-76)	(-79)	(79)	(-82)	(-82)
-72 (-76)	-71 (-76)	(79)	(79)	(-82)	(-82)
	<u>Standard</u> (-74) -73 (-77) -76 (-79) (-70) -73 (-76)	(-74) (-74) -73 (-77) -73 (-77) -76 (-79) -75 (-79) (-70) (-70) -73 (-76) -73 (-76)	Standard Option 506 Standard (-74) (-74) (-77) -73 (-77) -73 (-77) (-81) -76 (-79) -75 (-79) (-83) (-70) (-70) (-73) -73 (-76) -73 (-76) (-79)	Standard Option 506 Standard Option 506 (-74) (-74) (-77) (-77) -73 (-77) -73 (-77) -76 (-79) -75 (-79) (-70) (-70) (-73) (-73) -73 (-76) -73 (-79)	Standard Option 506 Standard Option 506 Standard (-74) (-74) (-77) (-77) (-77) -73 (-77) -73 (-77) (-77) -76 (-79) -75 (-79) (-83) (-83) (-85) (-70) (-70) (-70) (-73) (-73) (-76) -73 (-76) -73 (-79) (-79) (-82)

Rho¹[\leq 4 dBm standard and Option 506, or \leq 7 dBm Option UNB, IS-95 filter, \leq 2 GHz] $\rho \geq$ 0.9992 (.9998)

cdma2000

[arbitrary waveform mode] [Option 401]

Spurious emissions

[dBc, IS-95 modified filter with equalizer and amplitude = \leq -5 dBm standard, \leq -3 dBm for Option 506, \leq 0 dBm for Option UNB]

	Off	sets from center of carr	rier
Frequencies/offsets 2.1	35 to 2.50 MHz	2.50 to 3.23 MHz	3.23 to 10 MHz
Forward 9 channel, SR3/	/multi-carrier ^{1, 3}		
30 – 200 MHz	(70)	(-69)	(-69)
700 – 1000 MHz	(75)	(74)	(-77)
>1000 – 2000 MHz	(75)	(-74)	(-77)
Offsets	from center of car	rier	
Frequencies/offsets 2.6	655 to 3.75 MHz	3.75 to 5.94 MHz	5.94 to 10 MHz
Forward 9 channel, SR3/	⁄DS ^{1,4}		
30 – 200 MHz	(76)	(78)	(-75)
700 – 1000 MHz	(-80)	(-83)	(85)
>1000 – 2000 MHz	(80)	(-83)	(—85)
Reverse 5 channel, SR3/	′DS ^{1,3}		
30 – 200 MHz	(78)	(78)	(-75)
700 – 1000 MHz	(-82)	(-83)	(-85)
>1000 – 2000 MHz	(-82)	(-83)	(-85)
Error vector magnitude			

 $\leq 4 \text{ dBm}$ standard and Option 506, $\leq 7 \text{ dBm}$ for Option UNB

EVM $\leq 2.1\%, (\leq 1.5\%)$

^{[825} to 2100 MHz, SR3 pilot, IS-95 filter, which is optimized for EVM]¹

^{1.} Parentheses denote typical performance.

^{2.} Valid for 23° \pm 5° C.

^{3.} Measurements performed with 30 kHz BW, relative to power in one carrier.

^{4.} Measurements performed with 30 kHz BW, relative to total power.

Enhanced multitone¹

[arbitrary waveform mode] [Option 408]

Number of tones 2 to 1024 Tone spacing 1 kHz to 50 MHz, limited by 80 MHz I/Q bandwidt Tone power (relative) 0 to -50 dB Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced images)		
Tone power (relative) 0 to -50 dB Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Number of tones	2 to 1024
Phase distribution Fixed, random or parabolic Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Tone spacing	1 kHz to 50 MHz, limited by 80 MHz I/Q bandwidth
Suppression level -50 to -90 dBc, depending on number of tones and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Tone power (relative)	0 to -50 dB
and available calibration time. Expected suppression = 80 dBc -10 log [N/8], where N is the number of tones Calibration interval 8 hours Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Phase distribution	Fixed, random or parabolic
Calibration time 10 minutes (8 tones, -80 dBc suppression) Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Suppression level	and available calibration time. Expected suppression = 80 dBc -10 log [N/8],
Temperature stability 1 dB/°C (typical for IMD products) 5 dB/°C (worst case for LO feedthrough and unbalanced	Calibration interval	8 hours
(worst case for LO feedthrough and unbalanced	Calibration time	10 minutes (8 tones, -80 dBc suppression)
	Temperature stability	(worst case for LO feedthrough and unbalanced



Enhanced multitone signal with correction applied

Crest factor [output power set at least 16 dB below maximum power] > 16 dB					
Randomness	89 bit pseudo-random generation, repetition period 3 x 10 ⁹ years				
Carrier to noise ratio	Magnitude error \leq 0.2 dB at baseband I/Q outputs.				

AWGN

[real-time mode] [Option 403]

802.11 WLAN

[arbitrary waveform mode] [Option 417]¹

EVM

(< 1%, -40 dB)

The EVM was measured with an 89641A vector signal analyzer with Option B7R.

Instrument and software settings listed below.

ftware settings		Source settings	
Data rate	54 Mbps	Frequency	5.8/2.4/0.9 GHz
Modulation	64 QAM	Output power	≤ -1 dBm
Encoder	3/4 rate	Reconstruction filter	thru
Scrambler	active	ALC	On
interleaver	active	RF blanking	Off
Scrambler initialization	5D	Modulator Atten	8 to 10 dB
Support carrier setup	All channels	active	
Idle interval	100 µS	89641A settings	
OSR	≥2	Frequency	5.8/2.4/0.9 GHz
Window length	≥8	Span	20 MHz
Data type	PN15	Range	optimal
Data length	1024	RMS video average	20

802.11a spectral mask typical performance

(0 dbm, at 5.805 GHz, OSR: 4, window length: 16)

Ref -4.	00dBn	1		Spe	ctrum (Ref:	PSD)			
10.00	\square		[]							
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	Lower	~~~	www.w		+		<u> </u>	- Anner	100-5-16171	*****
	-							1		
	5.775	5 GHz		Abs Li	mit R	el Limi	t		5.8	875 GH
Total P	wr: -0.	36 dBm	/ 22.000	00 MHz	Peak F			40 dBm		
Start(H:	2)	Stop(Hz)	Meas B	W(Hz)	dE	B Ere	r eq(Hz)		dB Up	pper Freg(Hz
9.0000	M	11.000 M	10	0.00 k	-21.27	5.0	3160 G	-22.		5.8342
11.000		20.000 M		0.00 k	-32.13		3140 G	-33.		5.8362
20.000		30.000 M		0.00 k	-53.22		3049 G		76	5.8453
30.000	M	50.000 M	10	0.00 k	-66.71	5.	7876 G	-66.	61	5.8585

^{1.} All values typical.

Custom modulation

[real-time mode]

Custom digitally modulated signals [real-time mode]^{1,7}

Modulation	QPSK	ΔΡSK π/4D Δ PSK 16 Δ AM		2FSK	GMSK
Filter		Root Nyquist	1	Ga	nussian
Filter factor [a or $B_{b}T$]	0.25	0.25	0.25	0.5	0.5
Modulation index	N/A N/A		N/A	0.5	N/A
Symbol rate [Msym/s]	4 4		4	1	1
	Error vector magnitude ^{2, 6}			Shift error ^{2, 6}	Global phase error ^{2, 6}
		[% rms]		[% rms]	[degrees rms]
fc = 1 GHz	1.1 (0.7)	1.1 (0.7)	1.0 (0.6)	1.3 (0.8)	0.4 (0.2)
fc = 2 GHz	1.2 (0.8)	1.2 (0.8)	1.0 (0.6)	1.4 (0.9)	0.5 (0.3)
fc = 3 GHz	1.6 (1.0)	1.6 (1.0)	1.5 (0.9)	1.8 (1.0)	0.7 (0.4)
fc = 4 GHz	2.5 (1.4)	2.5 (1.3)	3.3 (1.9)	3.3 (2.0)	1.0 (0.6)
fc = 5 GHz	1.5 (1.0)	1.5 (1.0)	1.2 (0.8)	1.8 (1.2)	0.6 (0.3)
fc = 6 GHz	1.8 (1.2)	1.8 (1.2)	1.4 (1.0)	2.0 (1.4)	0.8 (0.4)

Internal modulation using real-time TDMA personalities [Option 402]⁷

~	NA	DC	PI	DC	Pl	IS	TET	RA ⁴	DECT	GSM D	CS, PCS	EDGE
Error vector magnitude ^{3, 6} [% rms]												
Low EVM mode	1.2	(0.7)	1.2	(0.7)	0.9	(0.5)	0.8	(0.5)				1.2 (0.6)
Low ACP mode	(1	.2)	(0	.9)	(0	.6)	(1	.0)				
Global phase error ³												
rms	N,	/A	N/	/A	N/	/A	N,	/A	N/A	0.6	(0.3)	N/A
pk										1.9	(1.0)	
Deviation accuracy ³ [kHz, rms]	N.	/Α	N/	/A	N/	/A	N,	/A	2.5 (1.1)	N	/A	N/A
Channel spacing [kHz]	3	0	2	5	30	00	2	5	1728	2	00	200
Adjacent channel power ³ [ACP]	Cont.	Burst	Cont.	Burst	Cont.	Burst	Cont.	Burst	N/A	Cont.	Burst	N/A
(Low ACP mode, dBc)												
at adjacent channel ⁵	(-35)	(-34)	-	-	-	-	(-70)	(-63)		(-37)	(-37)	
at 1st alternate channel ⁵	(-80)	(-79)	(-74)	(-74)	(-81)	(-76)	(-81)	(-80)		(-71)	(-70)	
at 2nd alternate channel ⁵	(-84)	(-83)	-	-	(-82)	(-79)	(-82)	(-82)		(-84)	(-81)	
at 3rd alternate channel ⁵	(-85)	(-84)	(-82)	(-82)	-	-	(-83)	(-83)		(-85)	(-81)	
Support burst types	Cus	tom	Cus	tom	Cus	tom	Cus	tom	Custom	Custom	, normal	
	up/dov	vn TCH	up/dov	vn TCH	TCH,	sync	up contr	ol 1 & 2,	dummy B 1 & 2,	Fcorr,	sync,	
			up	Vox			up no	rmal,	traffic B,	dummy	, access	
							down r	normal,	low capacity			
Scramble capability					Ye	es	Ye	es				

1. This level of performance can be attained using the external I/Q inputs, provided the quality of the baseband signal meets or exceeds that of the ESG baseband generator.

^{2.} Specifications apply at power levels \leq +4 dBm [\leq +5 dBm for Option 506, and \leq +8 dBm for Option UNB] with default scale factor of I/Q outputs.

Specifications apply for the symbol rates, filter, filter factors [a or BbT] and default scaling factor specified for each standard, and at power levels ≤ +7 dBm [≤ +10 dBm for Option UNB].

^{4.} ACP for TETRA is measured over a 25 kHz bandwidth, with an 18 kHz root raised cosine filter. Low ACP mode is valid at power levels ≤ -1 dBm [≤ 1 dBm for Option 506 and $\leq +4$ dBm for Option UNB].

^{5.} The "channel spacing" determines the offset size of the adjacent and alternate channels: Adjacent channel offset = 1 x channel spacing,

¹st alternate channel = 2 x channel spacing, 2nd alternate channel = 3 x channel spacing, etc.

^{6.} Valid after executing I/Q calibration and maintained within +/- 5 °C of the calibration temperature.

^{7.} Parentheses denote typical performance.

GSM/GPRS [real-time mode] [Option 402]

Coding scheme	Full-rate speech [TCH/FS]		
	CS-1, CS-4		
Data	PN9 or PN15		
	The selected data sequence is coded continuously		
	across the RLC data block as per ETSI TS 100 909, 30		
	TS 05.03, V8.9.0, 2000-11 [release 1999]		
	An independent version of the selected data sequen is coded across the MAC header.		
Frame structure	26-frame multi-frame structure as per ETSI		
Frame structure	GSM, 05.01 version 6.1.1 [1998-07].		
	[Coding is done on frames 0-11, 13-24, of the multi-fra		
	Frame 25 is idle [RF blanked].]		
Adjacent timeslots			
Data	PN9, PN15 coded as per ETSI TS 100 909, 3GPP		
	TS 05.03, V8.9.0, 2000-11 [release 1999].		
Frame structure	26-frame multi-frame structure as per ETSI GSM,		
	5.01 version 6.1.1 [1998-07].		
ultiframe measurements ¹			
GSM measurement modes			
Static sensitivity	RBER at user-specified power level measured. [This is the complete conformance test as defined ir		
	pri-ETS 300 609-1 [GSM 11.21] version 4.12.0 [Dec 9		
	section 7.3.4.]		
Sensitivity search	Automatically finds the input level [sensitivity] that ca		
	a user-specified RBER [normally 2%] for class II bits.		
Maximum frame cour	t 6,000,000 speech frames		
GSM measurement results	Class Ib bit-error ratio [RBER for TCH/FS]		
	Class II bit-error ratio [RBER for TCH/FS]		
	Frame erasure ratio [FER]		
	Downlink error frame count		
	Class Ib bit-error count Class II bit-error count		
	Class II bit-error count Erased frame count		
	Total frame count		
Maximum RBER	50%		

Alternate time slot power level control

[Valid for standard attenuator only. Not applicable to Option UNB or Option 506] Amplitude is settled within 0.5 dB in 20 µsecs, +4 to -136 dBm at 23 ±5 °C

EDGE/EGPRS [real-time mode] [Option 402]

Coding scheme	MCS-1: uplink and downlink, MCS-5: uplink and downlin		
-	MCS-9: uplink and downlink, E-TCH/F43.2		
Data	PN9 or PN15		
	The selected data sequence is fully coded		
	continuously across the RLC data blocks according to		
	MCS-1, MCS-5, MCS-9 or E-TCH/F43.2. An independer		
	version of the selected data sequence is coded across		
	unused RLC/MAC header fields [The CPS header field		
<u> </u>	as defined in GSM 04.60 V8.50].		
Frame structure	52-frame multi-frame structure for EDGE/EGPRS char as per ETSI TS 100 909, 3GPP TS 05.03, V8.9.0, 2000-1		
	[release 1999]. [Coding is done on frames 0-11, 13-24		
	26-37, 39-50 on a 52 PDCH multi-frame. Frame 25 and		
	51 are idle [RF blanked].]		
Adjacent timeslots			
Data	Coded MCS-1, MCS-5 or MCS-9 with continuous PN9		
	PN15 sequence data payload.		
	Uncoded PN9, PN15.		
	Note: Maximum of 4 timeslots can be turned on with		
Frame structure	EDGE/EGPRS multi-frame coded data. EDGE/EGPRS PDCH multi-frame.		
Frame structure	Repeating EDGE frame.		
ultiframe measurements ¹			
EDGE measurement modes			
Static sensitivity	BER/BLER at user-specified power level measured;		
	based on bit errors in total unencoded data, and blocl		
	errors in coded channels.		
Sensitivity search	Automatically finds the input level [sensitivity] that cau		
BER/BLER	user-specified BER [uncoded] or BER [coded].		
EDGE measurement results	Erased data block count/rate for coded channel		
	[MCS-1, MCS-5 or MCS-9].		
	Total data block count for coded channel		
	[MCS-1, MCS-5 or MCS-9]. Payload bit error count/rate for raw BER.		
	•		
	Intal burst count for raw RER Data block count which		
	Total burst count for raw BER. Data block count which contains residual bit errors and bit error count.		

GSM/EDGE base station bit error rate test [BERT] [Option 300]

This is a system of two instruments; an ESG with Option 300, and a VSA with Option 300. Both are required. Option 300 for the ESG requires Option 601 or 602, the TDMA personalities [Option 402], and the UN7 BER board. The VSA functions as an IF downconverter. It may be used simultaneously to make transmitter measurements on the loop back signal.

GSM BTS test only

E4406A VSA series transmitter tester with Options BAH [GSM measurement personality] and Option 300 [321.4 MHz output].

GSM/EDGE BTS test

E4406A VSA series transmitter tester with Option 202 [GSM and EDGE measurement personality] and Option 300 [321.4 MHz output].

Test technique	RF loopback
Supported systems GSM 400	
GSM 850	
GSM 900 [P-GSM]	
DCS 1800	
PCS 1900	
E-GSM [extended]	
Minimum power level	–136 dBm [ESG minimum]
Maximum power level	+13 dBm [option dependent]
Power level accuracy	$\pm 0.5~\text{dB}~[23^\circ\pm5~^\circ\text{C}]$ [power and frequency dependent]
Relative power level	0 to ± 130 dB relative to timeslot under test.
	[Limited only by output power range of the ESG.]
Timeslot under test	
Timeslots tested	0 to 7
	A single timeslot is tested at one time.
	[No frequency hopping.]
Encryption	None
Measurement triggers	Immediate, trigger key, external, remote [LAN, GPIB, RS-232]
Measurement indication	Pass/fail
BCH sync	BCH signal from the BTS is used to determine TCH frame and multi-frame location.
TCH sync	The idle frame [no RF] in the TCH signal itself is used to determine the TCH multi-frame location and so generate the multi-frame sync signal.
Threshold	Termination of measurement when error count exceeds user-specified threshold.

Bit error rate [BER] analyzer [Option UN7]

Clock rate 100 Hz to 60 MHz			
Supported data patterns	PN9, 11, 15, 20, 23		
Resolution	10 digits		
Bit sequence length 100 bits to 4.294 Gbits after synchronization			
Features			
	Input clock phase adjustment and gate delay		
	Adjustable input threshold		
	Hi/lo threshold selectable from 0.7 V [TTL], 1.4 V [TTL]		
	1.65 V [CMOS 3.3], 2.5 V [CMOS 5.0]		
	Direct measurement triggering		
	Data and reference signal outputs		
	Real-time display		
	Bit count		
	Error-bit-count		
	Bit error rate		
	Pass/fail indication		
	Valid data and clock detection		
	Automatic re-synchronization		
	Special pattern ignore		

Operating characteristics

Power requirements	90 to 254 V; 50, or 60 Hz; 300 W maximum, power factor corrected. Not for 400 MHz use. ³					
Operating temperature range ²	0 to 55 °C	0 to 55 °C				
Storage temperature range	–40 to 71 °C					
Shock and vibration	Meets MIL-STD	-28800E Type III, Clas	ss 3.			
Leakage	Conducted and radiated interference meets MIL-STD-461C CE02 Part 2 and CISPR 11. Leakage is typically < 1 μ V [nominally 0.1 μ V with a 2-turn loop] at \leq 1000 MHz, measured with a resonant dipole antenna, one inch from any surface with output level < 0 dBm [all inputs/outputs properly terminated].					
Storage registers	Memory is shared by instrument states, user data files, sweep list files and waveform sequences. Depending on the number and size of these files, up to 100 storage registers and 1000 register sequences [10 per register] are available.					
Weight	< 16 kg [35 lb.] r	net, < 23 kg [50 lb.] s	hipping			
Dimensions	133 mm H x 426 mm W x 432 mm D [5.25 in H x 16.8 in W x 17 in D]					
Remote programming						
Interface	GPIB [IEEE-488.2-1987] with listen and talk, RS-232, LAN [10BaseT].					
Control languages ¹	SCPI version 1996.0, also compatible with 8656B an 8657A/B/C/D/J1 mnemonics.		with 8656B and			
Functions controlled	All front panel fu	unctions except pow	er switch and knob.			
ISO compliant	The E4438C ESG is manufactured in an ISO-9001 registered facility in concurrence with Agilent Technologies commitment to quality.					
Reverse power protection	o		500			
	<i>Standard</i> 47 dBm	<u>With Option</u> 30 dBm	500			
	47 aBm 44 dBm	30 dBm 30 dBm				
	N/A	30 dBm				
	40 V	co ubiii				
SWR ⁴						
	Standard	Option UNB	Option 506			
250 kHz to 2.2 GHz	(< 1.5:1)	(< 1.5:1)	(< 1.6:1)			
> 2.2 GHz to 3 GHz	(< 1.4:1)	(< 1.5:1)	(< 1.4:1)			
> 3 GHz to 4 GHz	(< 1.5:1)	(< 1.7:1)	(< 1.7:1)			
> 4 GHz to 6 GHz	N/A	N/A	(< 1.8:1)			
Output impedance	50 Ω nominal					

- 3. For 400 MHz systems, order transformer 70001-60066.
- 4. Parentheses denote typical performance.

^{1.} ESG series does not implement 8657A/B "Standby" or "On" [R0 or R1, respectively] mnemonics.

^{2.} Save and recall of user files and instrument states from non-volatile storage is guaranteed only over the range 0 to 40 °C.

Accessories

Inputs and outputs

to rear with Option 1EM.

Transit case Part number 9211-1296 10 MHz input Accepts a 1, 2, 5, or 10 MHz ±10 ppm [standard timebase] All front panel connectors can be moved or ±1 ppm [high-stability timebase] reference signal for operation with an external timebase. Nominal input level –3.5 to +20 dBm, impedance 50 ohms. [BNC, rear panel] 10 MHz output Outputs the 10 MHz reference signal. Level nominally +3.9 dBm ±2 dB. Nominal output impedance 50 ohms. [BNC, rear panel] Accepts CMOS¹ signal for synchronization of external Alternate power input data and alternate power signal timing. The damage levels are -0.5 to +5.5 V. [Auxiliary I/O connector, rear panel] Baseband generator Accepts 0 to +20 dBm sinewave, or TTL squarewave, reference input to use as reference clock for the baseband generator. Phase locks the internal data generator to the external reference: the RF frequency is still locked to the 10 MHz reference. Rate is 250 kHz to 100 MHz, 50 ohms nominal, AC coupled. [BNC, rear panel] Burst gate input The burst gate in connector accepts a CMOS¹ signal for gating burst power in digital modulation applications. The burst gating is used when you are externally supplying data and clock information. The input signal must be synchronized with the external data input that will be output during the burst. The burst power envelope and modulated data are internally delayed and re-synchronized. The input signal must be CMOS high for normal burst RF power or CW RF output power and CMOS low for RF off. The damage levels are -0.5 to +5.5 V. This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector. With Option 401, this connector is used for the even second synchronization input. Coherent carrier output² Outputs RF modulated with FM or Φ M, but not IQ, pulse or AM. Nominal power -2 dBm ±5 dB. Nominal impedance 50 ohms. Frequency range from > 250 MHz to 4 GHz. For RF carriers below this range, output frequency = 1 GHz – frequency of RF output. Damage levels 20 VDC and 13 dBm reverse RF power. [SMA, rear panel]

1. Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

2. Coherent carrier is modulated by FM or Φ M when enabled.

Data clock input	The CMOS ¹ compatible data clock connector accepts an externally supplied data-clock input for digital modulation applications. The expected input is a bit clock signal where the falling edge is used to clock the data and symbol sync signals.
	The maximum clock rate is 50 MHz. The damage levels are –0.5 to +5.5 V.
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Data clock output	Relays a CMOS ¹ bit clock signal for synchronizing serial data. [Auxiliary I/O connector, rear panel]
Data input	The CMOS ¹ compatible data connector accepts an externally supplied data input for digital modulation applications. CMOS high is equivalent to a data 1 and a CMOS low is equivalent to a data 0.
	The maximum data rate is 50 Mb/s. The data must be valid on the data clock falling edges [normal mode] or the symbol sync falling edges [symbol mode]. The damage levels are –0.5 to +5.5 V.
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Data output	Outputs serial data from the internal data generator or the externally supplied signal at the data input. CMOS ¹ signal. [Auxiliary I/O connector, rear panel]
Event 1 output	In real-time mode, outputs pattern or frame synchronization pulse for triggering or gating external equipment. May be set to start at the beginning of a pattern, frame, or timeslot and is adjustable to within ± one timeslot with one bit resolution.
	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 1. [BNC, rear panel]
Event 2 output	In real-time mode, outputs data enable signal for gating external equipment. Applicable when external data is clocked into internally generated timeslots. Data is enabled when signal is low.
	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 2. [BNC, rear panel]
Event 3 output	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 3. [Auxiliary I/O connector, rear panel]
Event 4 output	In arbitrary waveform mode, this connector outputs the timing signal generated by marker 4. [Auxiliary I/O connector, rear panel]

External 1 input	This BNC input connector accepts a ±1 V _{peak} signal for AM, FM, pulse, burst, and phase modulation. For all these modulations, ±1 V _{peak} produces the indicated deviation or depth. When ac-coupled inputs are selected for AM, FM, or phase modulation and the peak input voltage differs from 1 V _{peak} by more than 3%, the hi/lo annunciator light on the display. The input impedance is 50 ohms and the damage levels are 5 V _{rms} and 10 V _{peak} .
	If you configure your signal generator with Option 1EM, this input is relocated to a female BNC connector on the rear panel.
External 2 input	This BNC input connector accepts a $\pm 1 V_{peak}$ signal for AM, FM, phase modulation, and pulse modulation. With AM, FM, or phase modulation, $\pm 1 V_{peak}$ produces the indicated deviation or depth. With pulse modulation, $\pm 1 V$ is on and 0 V is off. When ac-coupled inputs are selected for AM, FM, or phase modulation, and the peak voltage differs from 1 V_{peak} by more than 3%, the hi/lo annunciator light on the display. The input impedance is 50 ohms and the damage levels are 5 V_{rms} and 10 V_{peak} .
	If you configure your signal generator with Option 1EM, this input is relocated to a female BNC connector on the rear panel.
GPIB	Allows communication with compatible devices. [rear panel]
l input	Accepts an I input either for I/Q modulation or for wideband AM. Nominal input impedance 50 or 600 ohms. Damage levels are 1 V _{rms} and 10 V _{peak} . [BNC, front panel]
l out and Ω out ¹	The I out and Q out connectors output the analog components of I/Q modulation from the internal baseband generator. The nominal output impedance of these connectors are 50 Ω , DC-coupled. The damage levels are > +3.5 V and < -3.5 V. The output signal levels into a 50 Ω load are as follows: • (0.5 V _{peak}), corresponds to one unit length of the I/Q vector. • (0.7 V _{peak}), for peaks for π /4 DQPSK. • (1.6 V _{p-p}) maximum [Options 601, 602, 001, 002 only].
	These female BNC connectors are provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, these inputs are relocated to rear panel SMB connectors.

$\overline{I} \text{ and } \overline{\Omega} \text{ out }$	\overline{I} and $\overline{\Omega}$ are used in conjunction with I and Q to provide a balanced baseband stimulus. Balanced signals are signals present in two separate conductors that are symmetrical about the common mode offset, and are opposite in polarity [180 degrees out of phase].
	These female BNC connectors are provided only on signal generators with Option 601 or 602. If you configure your signal generator with Option 1EM, these inputs are relocated to rear panel SMB connectors.
LF output	Outputs the internally-generated LF source. Outputs 0 to 2.5 V _{peak} into 50 ohms, or 0 to 5 V _{peak} into high impedance. [BNC, front panel]
Pattern trigger input	Accepts CMOS ¹ signal to trigger internal pattern or frame generator to start single pattern output. Minimum pulse width 100 ns. The damage levels are –0.5 to +5.5 V. [BNC, rear panel]
Q input	Accepts a Q input for I/Q modulation. Nominal input impedance 50 or 600 ohms, damage levels are 1 V _{rms} and 10 V _{peak} . [BNC, front panel]
RF output	Nominal output impedance 50 ohms. [type-N female, front panel]
Sweep output	Generates output voltage, 0 to +10 V when signal generator is sweeping. Output impedance < 1 ohm, can drive 2000 ohms. [BNC, rear panel]
Symbol sync input	The CMOS ¹ compatible symbol sync connector accepts an externally supplied symbol sync for digital modulation applications. The expected input is a symbol clock signal. It may be used in two modes. When used as a symbol sync in conjunction with a data clock, the signal must be high during the first data bit of the symbol. The signal must be valid during the falling edge of the data clock signal and may be a single pulse or continuous. When the symbol sync itself is used as the [symbol] clock, the falling edge is used to clock the data signal.
	The maximum clock rate is 50 MHz. The damage levels are –0.5 to +5.5 V. [BNC, front panel]
	This female BNC connector is provided on signal generators with Option 601 or 602. On signal generators with Option 1EM, this input is relocated to a rear panel SMB connector.
Symbol sync output	Outputs CMOS ¹ symbol clock for symbol synchronization, one data clock period wide. [Auxiliary I/O connector, rear panel]
Trigger input	Accepts CMOS ¹ signal for triggering point-to-point in manual sweep mode, or to trigger start of LF sweep. the damage levels are –0.5 to +5.5 V. [BNC, rear panel]
Trigger output	Outputs a TTL signal: high at start of dwell, or when waiting for point trigger in manual sweep mode; low when dwell is over or point trigger is received, high or low 2 µs pulse at start of LF sweep. [BNC, rear panel]

With Option UN7	
BER data, BER clock BER gate	Accepts CMOS ¹ or 75 Ω input. Polarity is selected. Clock duty and inputs cycle is 30% to 70%. [SMB, rear panel]
BER sync loss output	Outputs a CMOS ¹ signal that is low when sync is lost. Valid only when measure end signal is high. [Auxiliary I/O connector, rear panel]
BER no data output	Outputs a CMOS ¹ signal that is low when no data is detected. Valid only when measure end is high. [Auxiliary I/O connector, rear panel]
BER error-bit-output	Outputs CMOS ^1 signal when error bit is detected. Pulse width matches the input clock. [Auxiliary I/O connector, rear panel]
BER test result output	Outputs a CMOS ¹ signal that is high for fail and low for pass. Valid only on measure end signal falling edge. [Auxiliary I/O connector, rear panel]
BER measure end output	Outputs a CMOS ¹ signal that is high during measurement. Trigger events are ignored while high. [Auxiliary I/O connector, rear panel]
BER measure trigger	Accepts CMOS ¹ signal to initiate BER measurement. Polarity is selectable; available when trigger source is selected as "AUX I/O". Damage levels are The damage levels are –0.5 to +5.5 V. [Auxiliary I/O connector, rear panel]
With Option 300	
321.4 MHz input	Accepts a 321.4 MHz IF signal for GSM/EDGE/loopback testing. Input amplitude range -7 dBm to -22 dBm. Nominal input impedance 50 ohms. [SMB, rear panel]

LAN connector

LAN communication is supported by the signal generator via the LAN connector. It is functionally equivalent to the GPIB connector. The LAN connector enables the signal generator to be remotely programmed by a LAN-connected computer. The distance between a computer and the signal generator is limited to 100 meters [10BaseT]. For more information about the LAN, refer to the *Getting Started* chapter in the *Programming Guide*.

Data transfer speeds ²		
LAN [FTP]	file transfer to volatile memory	(700 KB/sec)
	to hard drive	(500 KB/sec)
LAN [SCPI]	command transfer to volatile memory	(146 KB/sec)
	to hard drive	(128 KB/sec)
Internal file transf	er from hard drive to volatile memory	(1280 KB/sec)

2. Parentheses denote typical performance.

^{1.} Rear panel inputs and outputs are 3.3 V CMOS, unless indicated otherwise. CMOS inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

RS-232 connector

This male DB-9 connector is an RS-232 serial port that can be used for controlling the signal generator remotely. It is functionally equivalent to the GPIB connector. The following table shows the description of the pinouts. The pin configuration is shown below.

Pin number	Signal description	Signal name
1	No connection	
2	Receive data	RECV
3	Transmit data	XMIT
4	+5 V	
5	Ground, 0 V	
6	No connection	
7	Request to send	RTS
8	Clear to send	CTS
9	No connection	



View looking into rear panel connector

Auxiliary I/O connector

This connector enables you to access the inputs and outputs of the baseband generator. The figure below shows the Auxiliary I/O pin connector configuration.



View looking into rear panel connector

Mating connector

37 pin male D-subminiature, available from AMP, 3M, others.

Ordering Information¹

Frequency options	
requercy options	• 501 1 GHz frequency range
	• 502 2 GHz frequency range
	• 503 3 GHz frequency range
	• 504 4 GHz frequency range
	• 506 6 GHz frequency range [requires option UNJ, includes mechanical attenuator]
Performance enhancement options	UNB High output power with mechanical attenuator
	[included with 506]
	UNJ Enhanced phase noise performance
	[includes 1E5]
	1E5 High-stability time base
	1EM Moves all front panel connectors to rear
	 003² ESG digital output connectivity with N5102A Baseband Studio digital interface module
	 004² ESG digital input connectivity with N5102A Baseband Studio digital interface module
	• 601 Internal baseband generator with 8 MSa and digital bus capability
	 [40 MB] of memory 602 Internal baseband generator with 64 MSa and digital bus capability
	[320 MB] of memory
	• 005 ³ 6 GB internal hard drive
	UN7 Internal bit-error-rate analyzer
	300 GSM/EDGE base station loopback BERT
_	
Signal creation software ³	
Signal creation software ³	GGPP W-CDMA FDD personality
Signal creation software ³	cdma2000 and IS-95-A personality
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA)
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for HSDPA over W-CDMA
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for HSDPA over W-CDMA Signal Studio for TD-SCDMA (TSM)
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for noise power ratio (NPR)
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth™ Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for noise power ratio (NPR) Signal Studio for S-DMB
Signal creation software ³	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for noise power ratio (NPR)
	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for HSDPA over W-CDMA Signal Studio for noise power ratio (NPR) Signal Studio for S-DMB Signal Studio for pulse building
Signal creation software ³ Baseband Studio products ⁴	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for S-DMB Signal Studio for pulse building N5102A Baseband Studio digital signal interface module
	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for s-DMB Signal Studio for pulse building
	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for noise power ratio (NPR) Signal Studio for S-DMB Signal Studio for pulse building
	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for s-DMB Signal Studio for pulse building
	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for S-DMB Signal Studio for pulse building • N5102A Baseband Studio digital signal interface module N5110A Baseband Studio for waveform streaming⁵ N5101A Baseband Studio PCI card⁵
Baseband Studio products ⁴	 cdma2000 and IS-95-A personality TDMA personality (GSM, EDGE, GPRS, EGPRS, NADC, PDC, PHS, DECT, TETRA) Calibrated noise (AWGN) personality GPS personality Signal Studio for 1xEV-D0 Signal Studio for 1xEV-DV and cdma2000 Signal Studio for 802.11 WLAN Signal Studio for Bluetooth[™] Signal Studio for enhanced multitone Signal Studio for TD-SCDMA (TSM) Signal Studio for noise power ratio (NPR) Signal Studio for S-DMB Signal Studio for pulse building

^{1.} All options should be ordered using E4438C-xxx, where the xxx represents the option number. For more information, please refer to the configuration guide publication number 5988-4085EN.

- 3. Requuires Option 001, 002, 601, or 602.
- 4. Agilent's Baseband Studio is a suite of baseband signal applications and accessories that initially work with the E4438C ESG and E8267C PSG vector signal generators to enhance Agilent's signal creation and signal generation tool set. For details visit www.agilent.com/find/basebandstudio.
- 5. Baseband Studio for waveform streaming and for fading both require a PC equipped with the Agilent N5101A Baseband Studio PCI card. The PCI card is not functional as a stand-alone product.

^{2.} Requires either Option 601 or 602 (baseband generator) to function.

Related Literature

Application literature	
	• RF Source Basics, a self-paced tutorial (CD-ROM),
	literature number 5980-2060E.
	• Digital Modulation in Communications Systems–An Introduction,
	Application Note 1298, literature number 5965-7160E.
	 Using Vector Modulation Analysis in the Integration, Troubleshooting and Design of Digital Communications Systems, Product Note, literature number 5091-8687E. Testing CDMA Base Station Amplifiers, Application Note 1307, literature number 5967-5486E. Understanding CSM/EDCE Transmitter and Baseiner Magazine meta for
	• Understanding GSM/EDGE Transmitter and Receiver Measurements for Base Transceiver Stations and Their Components, Application Note 1312, literature number 5968-2320E.
	 Understanding CDMA Measurements for Base Stations and their Components, Application Note 1311, literature number 5968-0953E. Testing and Troubleshooting Digital RF Communications Receiver Designs, Application Note 1214, literature number 5068, 2570E
	 Designs, Application Note 1314, literature number 5968-3579E. Signal Generators - Vector, Analog, and CW Models, Selection Guide, literature number 5965-3094E.
Product literature	 E4438C ESG Vector Signal Generator, Brochure, literature number 5988-3935EN. E4438C ESG Vector Signal Generator, Configuration Guide, literature number 5988-4085EN. IntuiLink Software, Data Sheet, literature number 5980-3115EN.
	FAA200 FSC signal association firmulate networkeliding
	 E4438C ESG signal generation firmware personalities <i>3GPP W-CDMA (FDD) Personalities - Option 400</i>, Technical Overview, literature number 5988-4449EN
	 cdma2000 and IS-95A Personalities - Option 401, Technical Overview, literature number 5988-4430EN
	• GPS Personality - Option 409, Technical Overview,
	literature number 5988-6256EN
	• TDMA Personalities (GSM/EDGE/NADC/PDC/PHS/TETRA/DECT) - Option 402, Technical Overview, literature number 5988-4431EN
	E4438C ESG Signal Studio software personalities
	• Signal Studio for 1xEV-DO - Option 404, Technical Overview,
	literature number 5988-5459EN

- Signal Studio for 1xEV-DV and cdma2000 Option 414, Technical Overview, literature number 5988-9123EN
- Signal Studio for 802.11 WLAN Option 417, Technical Overview, literature number 5988-8618EN
- Signal Studio for Bluetooth Option 406, Technical Overview, literature number 5988-5458EN
- Signal Studio for Enhanced Multitone Option 408, Technical Overview, literature number 5988-5639EN
- Signal Studio for Noise Power Ratio Option 421, Technical Overview, literature number 5988-6552EN
- Signal Studio for TD-SCDMA (TSM) Option 411, Technical Overview, literature number 5988-6552EN

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